



STPS4045CP/CW

POWER SCHOTTKY RECTIFIERS

MAIN PRODUCTS CHARACTERISTICS

$I_{F(av)}$	2 x 20 A
V_{RRM}	45 V
$T_j(max)$	175 °C
$V_F(max)$	0.63 V

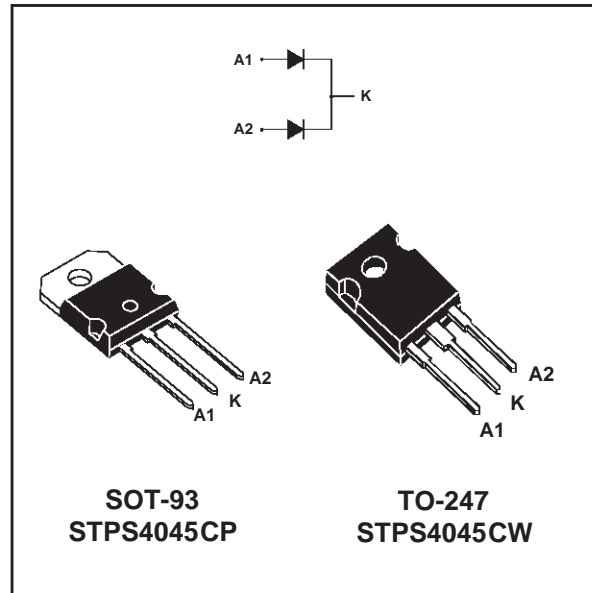
FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW THERMAL RESISTANCE

DESCRIPTION

Dual center tap Schottky rectifier suited for switchmode power supply and high frequency DC to DC converters.

Packaged either in SOT-93 or TO-247 this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		45	V
$I_{F(RMS)}$	RMS forward current		30	A
$I_{F(AV)}$	Average forward current	$T_c = 150^\circ\text{C}$ $\delta = 0.5$	Per diode 20 Per device 40	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10 \text{ ms}$ sinusoidal	220	A
I_{RRM}	Repetitive Peak reverse current	$t_p = 2 \mu\text{s}$ square $F = 1 \text{ kHz}$	1	A
I_{RSM}	Non repetitive peak reverse current	$t_p = 100 \mu\text{s}$ square	3	A
T_{stg}	Storage temperature range		- 65 to + 175	°C
T_j	Maximum operating junction temperature *		175	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/ μs

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

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THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction to case	Per diode	1.5	°C/W
		total	0.8	
R _{th(c)}		Coupling	0.1	

When the diodes 1 and 2 are used simultaneously :
 $\Delta T_J(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}			200	μA
		T _j = 125°C			11	40	mA
V _F *	Forward voltage drop	T _j = 125°C	I _F = 20 A		0.56	0.63	V
		T _j = 25°C	I _F = 40 A			0.94	
		T _j = 125°C	I _F = 40 A		0.7	0.83	

Pulse test : * t_p = 380 μs, δ < 2%

To evaluate the conduction losses use the following equation :

$$P = 0.46 \times I_{F(AV)} + 0.0085 I_{F(RMS)}^2$$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

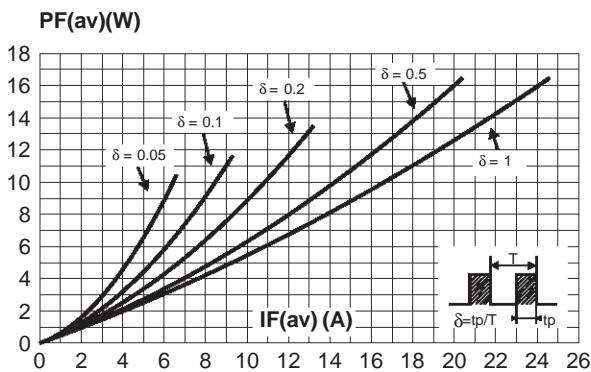


Fig. 2: Average current versus ambient temperature (per diode).

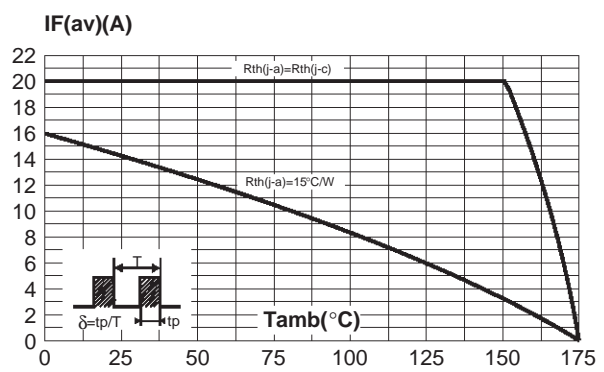


Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values) (per diode).

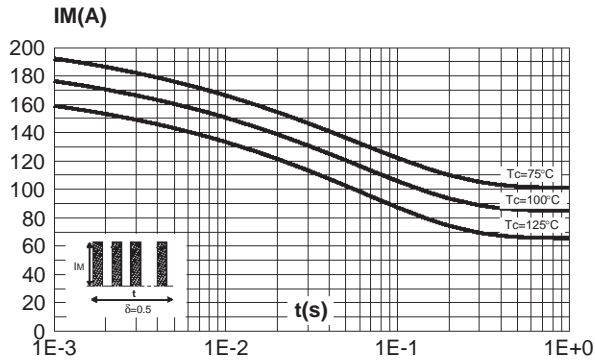


Fig. 4: Relative variation of thermal transient impedance junction to case versus pulse duration.

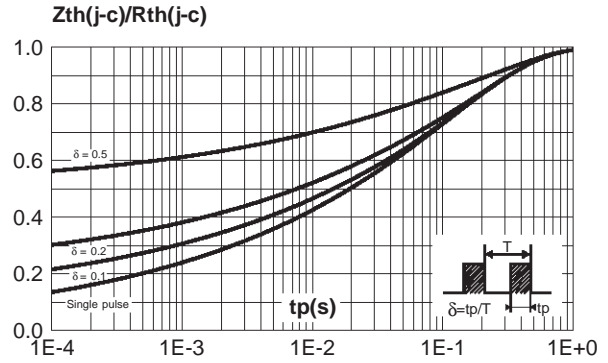


Fig. 5: Reverse leakage current versus reverse voltage applied (typical values) (per diode).

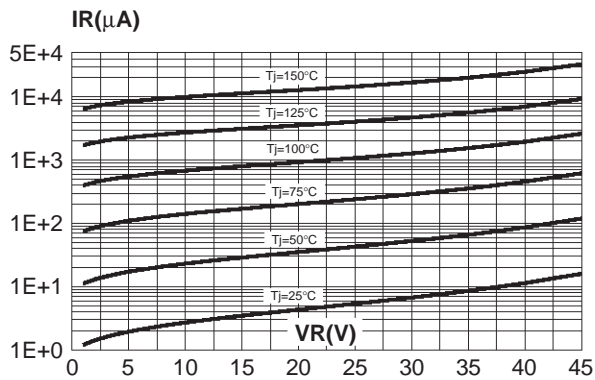


Fig. 6: Junction capacitance versus reverse voltage applied (typical values) (per diode).

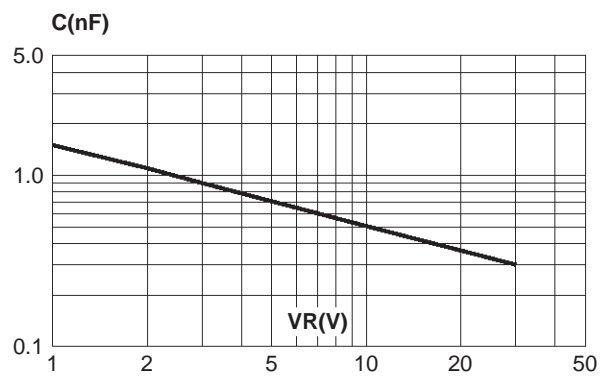
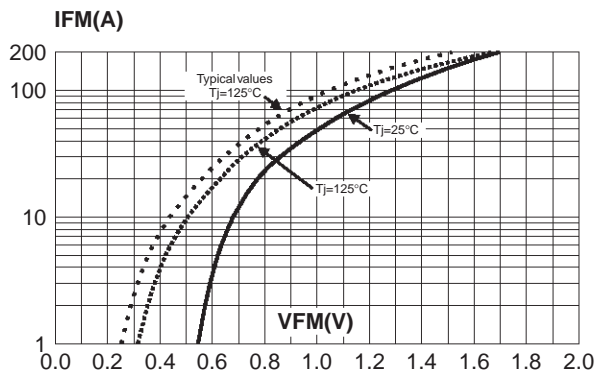
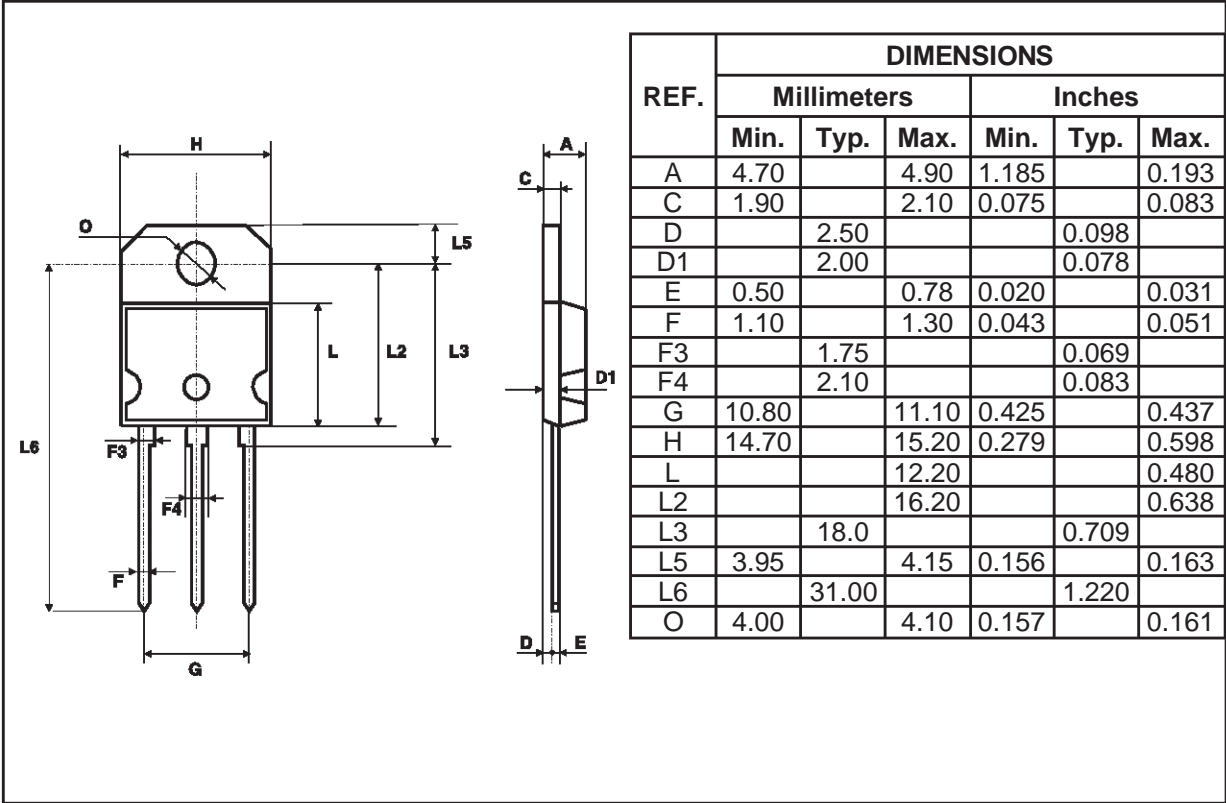


Fig. 7: Forward voltage drop versus forward current (maximum values) (per diode).

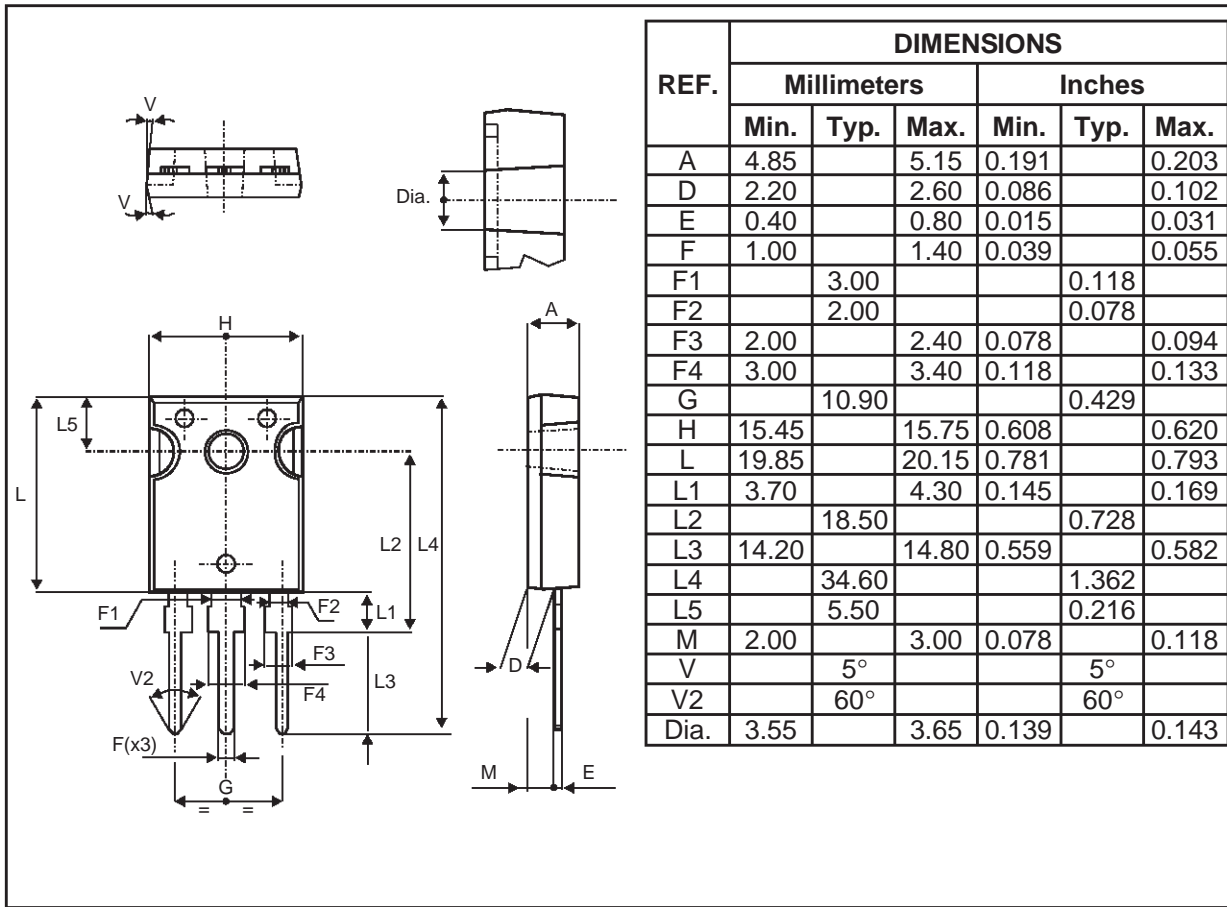


STPS4045CP/CW

PACKAGE MECHANICAL DATA
SOT-93



PACKAGE MECHANICAL DATA
TO-247



Type	Marking	Package	Weight	Base qty	Delivery mode
STPS4045CP	STPS4045CP	SOT-93	3.97 g.	30	Tube
STPS4045CW	STPS4045CW	TO-247	4.46 g.	30	Tube

- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N.m
- Maximum torque value: 1.0 N.m.
- Epoxy meets UL94,V0

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